SCBS225C - JUNE 1992 - REVISED MAY 1997

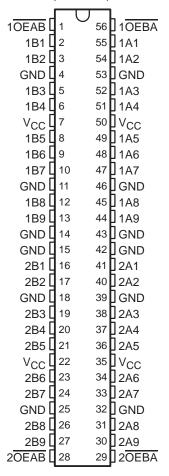
- Members of the Texas Instruments Widebus™ Family
- State-of-the-Art EPIC-IIB™ BiCMOS Design Significantly Reduces Power Dissipation
- Latch-Up Performance Exceeds 500 mA Per JEDEC Standard JESD-17
- Typical V<sub>OLP</sub> (Output Ground Bounce) < 1 V at V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25°C
- High-Impedance State During Power Up and Power Down
- Distributed V<sub>CC</sub> and GND Pin Configuration Minimizes High-Speed Switching Noise
- Flow-Through Architecture Optimizes PCB Layout
- High-Drive Outputs (–32-mA I<sub>OH</sub>, 64-mA I<sub>OL</sub>)
- Package Options Include Plastic 300-mil Shrink Small-Outline (DL) Package and 380-mil Fine-Pitch Ceramic Flat (WD) Package Using 25-mil Center-to-Center Spacings

#### description

The 'ABT16863 are 18-bit noninverting transceivers designed for asynchronous communication between data buses. The control-function implementation minimizes external timing requirements.

The 'ABT16863 can be used as two 9-bit transceivers or one 18-bit transceiver. They allow data transmission from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the output-enable (OEAB or OEBA) inputs.

SN54ABT16863 ... WD PACKAGE SN74ABT16863 ... DL PACKAGE (TOP VIEW)



When  $V_{CC}$  is between 0 and 2.1 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 2.1 V,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN54ABT16863 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74ABT16863 is characterized for operation from –40°C to 85°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

Widebus and EPIC-IIB are trademarks of Texas Instruments Incorporated.

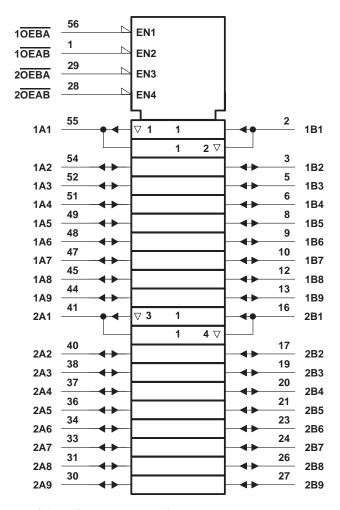


SCBS225C - JUNE 1992 - REVISED MAY 1997

# FUNCTION TABLE (each 9-bit section)

INP	UTS	OPERATION				
OEAB	OEBA					
Н	L	B data to A bus				
L	Н	A data to B bus				
Н	Н	Isolation				

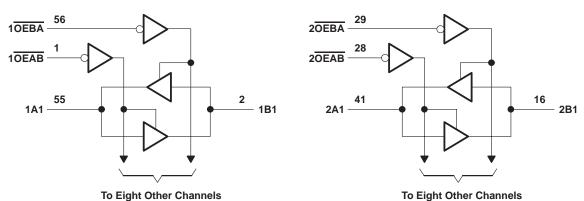
## logic symbol†



 $<sup>\</sup>ensuremath{^{\dagger}}$  This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.



#### logic diagram (positive logic)



#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V <sub>CC</sub>	
Voltage range applied to any output in the high or power-off state, V <sub>O</sub>	
Current into any output in the low state, I <sub>O</sub> : SN54ABT16863	96 mA
SN74ABT16863	128 mA
Input clamp current, I <sub>IK</sub> (V <sub>I</sub> < 0)	–18 mA
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0)	–50 mA
Package thermal impedance, θ <sub>JA</sub> (see Note 2): DL package	74°C/W
Storage temperature range, T <sub>stq</sub>	

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

2. The package thermal impedance is calculated in accordance with EIA/JEDEC Std JESD51.

#### recommended operating conditions (see Note 3)

			SN54ABT16863		SN74ABT16863		UNIT
			MIN	MAX	MIN	MAX	UNIT
Vcc	V <sub>CC</sub> Supply voltage				4.5	5.5	V
VIH	/IH High-level input voltage				2		V
V <sub>IL</sub>	Low-level input voltage					0.8	V
VI	Input voltage			Vcc	0	VCC	V
IOH	High-level output current		4	-24		-32	mA
lOL	Low-level output current		200	48		64	mA
Δt/Δν	Input transition rise or fall rate	Outputs enabled	000	10		10	ns/V
Δt/ΔV <sub>CC</sub>	Power-up ramp rate	•	200		200		μs/V
T <sub>A</sub>	Operating free-air temperature		-55	125	-40	85	°C

NOTE 3: Unused pins (input or I/O) must be held high or low to prevent them from floating.



SCBS225C - JUNE 1992 - REVISED MAY 1997

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		Т	T <sub>A</sub> = 25°C			SN54ABT16863		SN74ABT16863	
				MIN	TYP†	MAX	MIN	MAX	MIN	MAX	UNIT
VIK		$V_{CC} = 4.5 \text{ V},$	I <sub>I</sub> = -18 mA			-1.2		-1.2		-1.2	V
		$V_{CC} = 4.5 \text{ V},$	$I_{OH} = -3 \text{ mA}$	2.5			2.5		2.5		
V		V <sub>CC</sub> = 5 V,	$I_{OH} = -3 \text{ mA}$	3			3		3		V
VOH		V <sub>CC</sub> = 4.5 V	$I_{OH} = -24 \text{ mA}$	2			2				V
			$I_{OH} = -32 \text{ mA}$	2*					2		
VoL		V <sub>CC</sub> = 4.5 V	I <sub>OL</sub> = 48 mA			0.55		0.55			V
VOL		VCC = 4.5 V	I <sub>OL</sub> = 64 mA			0.55*				0.55	V
$V_{hys}$		<u> </u>			100						mV
	Control inputs	$V_{CC} = 0 \text{ to } 5.5 \text{ V, V}$	I = V <sub>CC</sub> or GND			±1		±1		±1	
lį	A or B ports	$V_{CC} = 2.1 \text{ V to } 5.5 \text{ V}_{I} = V_{CC} \text{ or GND}$	V,			±20		±20		±20	μΑ
+ V <sub>CC</sub> = 0 to 2.1 \		V <sub>CC</sub> = 0 to 2.1 V, V <sub>O</sub> = 0.5 V to 2.7 V	, <del>OE</del> = X			±50		±50		±50	μΑ
l <sub>OZPD</sub> ‡	:	$V_{CC} = 2.1 \text{ V to } 0,$ $V_{O} = 0.5 \text{ V to } 2.7 \text{ V}$	, <del>OE</del> = X			±50		±50		±50	μΑ
I <sub>OZH</sub> § V <sub>CC</sub> = V <sub>O</sub> = 2		$V_{CC} = 2.1 \text{ V} \text{ to } 5.5 \text{ V},$ $V_{O} = 2.7 \text{ V}, \overline{OE} \ge 2 \text{ V}$				10	(C)	10		10	μΑ
I <sub>OZL</sub> § VCC		$V_{CC} = 2.1 \text{ V} \text{ to } 5.5$ $V_{O} = 0.5 \text{ V}, \text{ OE } \ge 2$	V, V			-10	2008	-10		-10	μΑ
l <sub>off</sub>		$V_{CC} = 0$ ,	$V_I$ or $V_O \le 4.5 \text{ V}$			±100	Q.			±100	μΑ
ICEX	Outputs high	$V_{CC} = 5.5 \text{ V},$	V <sub>O</sub> = 5.5 V			50		50		50	μΑ
IOI		V <sub>CC</sub> = 5.5 V,	V <sub>O</sub> = 2.5 V	-50	-100	-180	-50	-180	-50	-180	mA
		V <sub>CC</sub> = 5.5 V,	Outputs high			2		2		2	mA
ICC	A or B ports		Outputs low			32		32		32	
			Outputs disabled			2		2		2	
ΔI <sub>CC</sub> #	Data inputs  VCC = 5.5 V, One input at 3.4 V, Other inputs at VCC or GND	One input at	Outputs enabled			1		1.5		1	
		Other inputs at	Outputs disabled			0.05		0.05		0.05	mA
	Control inputs	V <sub>CC</sub> = 5.5 V, One input at 3.4 V, Other inputs at V <sub>CC</sub> or GND				1.5		1.5		1.5	
Ci	Control inputs	V <sub>I</sub> = 2.5 V or 0.5 V			3.5						pF
C <sub>io</sub>	A or B ports	V <sub>O</sub> = 2.5 V or 0.5 V			9.5						pF

<sup>\*</sup> On products compliant to MIL-PRF-38535, this parameter does not apply.

<sup>&</sup>lt;sup>†</sup> All typical values are at  $V_{CC} = 5 \text{ V}$ .

<sup>‡</sup>This parameter is characterized, but not production tested.

<sup>§</sup> The parameters IOZH and IOZL include the input leakage current.

<sup>¶</sup> Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

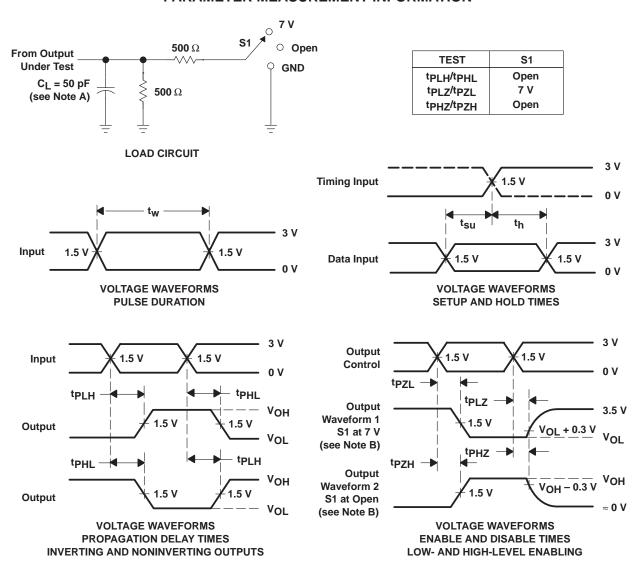
<sup>#</sup> This is the increase in supply current for each input that is at the specified TTL voltage level rather than V<sub>CC</sub> or GND.

SCBS225C - JUNE 1992 - REVISED MAY 1997

# switching characteristics over recommended ranges of supply voltage and operating free-air temperature, $C_L$ = 50 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 5 V, T <sub>A</sub> = 25°C			SN54ABT16863		SN74ABT16863		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t <sub>PLH</sub>	A or B	B or A	1	2.2	3.2	1	3.7	1	3.5	ns
<sup>t</sup> PHL			1	2.2	3.4	1 0	4.2	1	3.9	
<sup>t</sup> PZH	OEBA or OEAB	A or B	1	2.9	4.5	12	5.7	1	5.4	ns
t <sub>PZL</sub>			1	2.6	4.1	59	5.2	1	4.8	
t <sub>PHZ</sub>	OEBA or OEAB	A or D	1.6	4.1	5.4	01.6	6.3	1.6	6	
t <sub>PLZ</sub>		A or B	1.5	3.3	4.5	1.5	5.3	1.5	5	ns

#### PARAMETER MEASUREMENT INFORMATION



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50~\Omega$ ,  $t_f \leq$  2.5 ns.  $t_f \leq$  2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



#### **IMPORTANT NOTICE**

Texas Instruments and its subsidiaries (TI) reserve the right to make changes to their products or to discontinue any product or service without notice, and advise customers to obtain the latest version of relevant information to verify, before placing orders, that information being relied on is current and complete. All products are sold subject to the terms and conditions of sale supplied at the time of order acknowledgement, including those pertaining to warranty, patent infringement, and limitation of liability.

TI warrants performance of its semiconductor products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

CERTAIN APPLICATIONS USING SEMICONDUCTOR PRODUCTS MAY INVOLVE POTENTIAL RISKS OF DEATH, PERSONAL INJURY, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE ("CRITICAL APPLICATIONS"). TI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT DEVICES OR SYSTEMS OR OTHER CRITICAL APPLICATIONS. INCLUSION OF TI PRODUCTS IN SUCH APPLICATIONS IS UNDERSTOOD TO BE FULLY AT THE CUSTOMER'S RISK.

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards must be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance or customer product design. TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used. TI's publication of information regarding any third party's products or services does not constitute TI's approval, warranty or endorsement thereof.

Copyright © 1998, Texas Instruments Incorporated